

Dual N-Channel 60-V (D-S), 175°C MOSFET

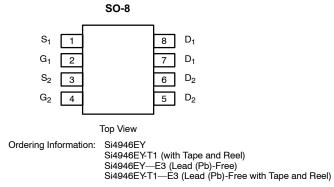
PRODUCT SUMMARY			
V _{DS} (V)	r _{DS(on)} (Ω)	I _D (A)	
60	0.055 @ V _{GS} = 10 V	4.5	
	0.075 @ V _{GS} = 4.5 V	3.9	

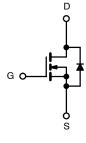
FEATURES

- TrenchFET[®] Power MOSFET
- 175°C Maximum Junction Temperature
- 100% R_g Tested



Pb-free Available





N-Channel MOSFET

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	60		
Gate-Source Voltage		V _{GS}	±20	V	
	$T_A = 25^{\circ}C$		4.5		
Continuous Drain Current (T _J = 175°C) ^a	$T_A = 70^{\circ}C$	I _D	3.8		
Pulsed Drain Current		I _{DM}	30	Α	
Continuous Source Current (Diode Conduction) ^a	I _S	2			
Single Avalanche Current		I _{AS}	12		
Single Avalanche Energy	L = 0.1 mH	E _{AS}	7.2	mJ	
	$T_A = 25^{\circ}C$	_	2.4		
Maximum Power Dissipation ^a	$T_A = 70^{\circ}C$	PD	1.7	W	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to 175	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Maximum Junction-to-Ambient ^a	R _{thJA}	62.5	°C/W		

Notes

a. Surface Mounted on FR4 Board, t \leq 10 sec.

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SPECIFICATIONS (T _J = 25° C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Test Condition	Min	Typ ^a	Max	Unit	
Static					•		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1		3	V	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS} —	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			2		
		V_{DS} = 60 V, V_{GS} = 0 V, T_J = 55 $^\circ C$			25	μA	
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	20			А	
	_	V_{GS} = 10 V, I _D = 4.5 A		0.045	0.055	Ω	
Drain-Source On-State Resistance ^b	r _{DS(on)}	V_{GS} = 4.5 V, I _D = 3.9 A		0.055	0.075		
Forward Transconductanceb	9fs	$V_{DS} = 15 \text{ V}, I_D = 4.5 \text{ A}$		13		S	
Diode Forward Voltage ^b	V _{SD}	$I_{S} = 2 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$		0.9	1.2	V	
Dynamic ^a							
Total Gate Charge	Qg			19	30	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = 30 V, $~V_{GS}$ = 10 V, I_{D} = 4.5 A		4			
Gate-Drain Charge	Q _{gd}			3			
Gate Resistance	Rg		1		3.6	Ω	
Turn-On Delay Time	t _{d(on)}			13	20	ns	
Rise Time	t _r	$\begin{array}{l} V_{DD} \texttt{= 30 V, } R_L \texttt{= 30 } \Omega \\ I_D \cong \texttt{ 1 A, } V_{GEN} \texttt{= 10 V, } R_G \texttt{= 6 } \Omega \end{array}$		11	20		
Turn-Off Delay Time	t _{d(off)}			36	60		
Fall Time	t _f			11	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2 A, di/dt = 100 A/μs		35	60	1	

Notes

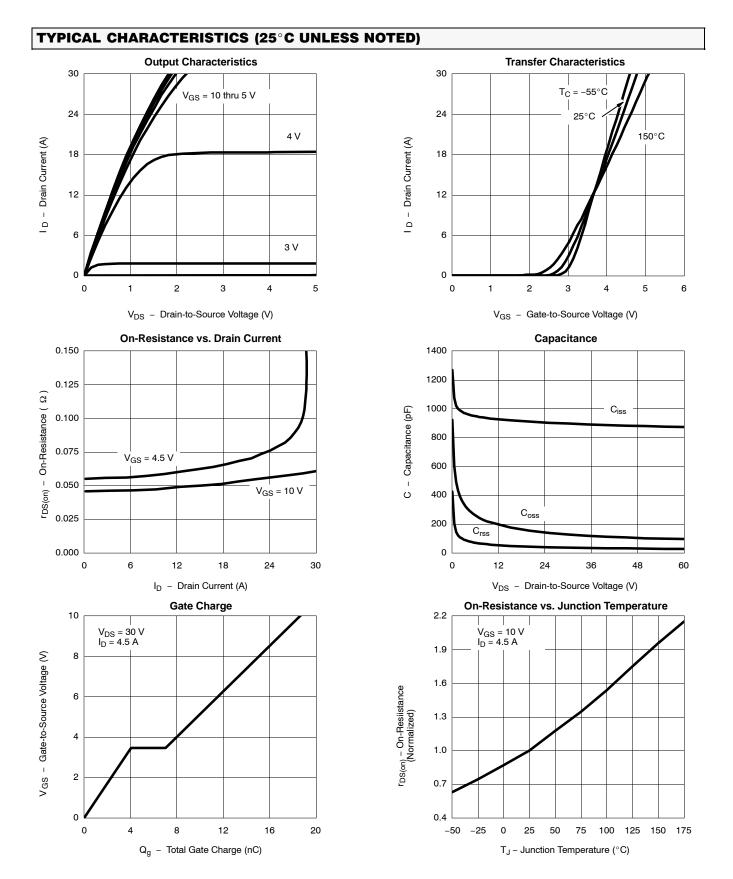
a.

For design aid only; not subject to production testing. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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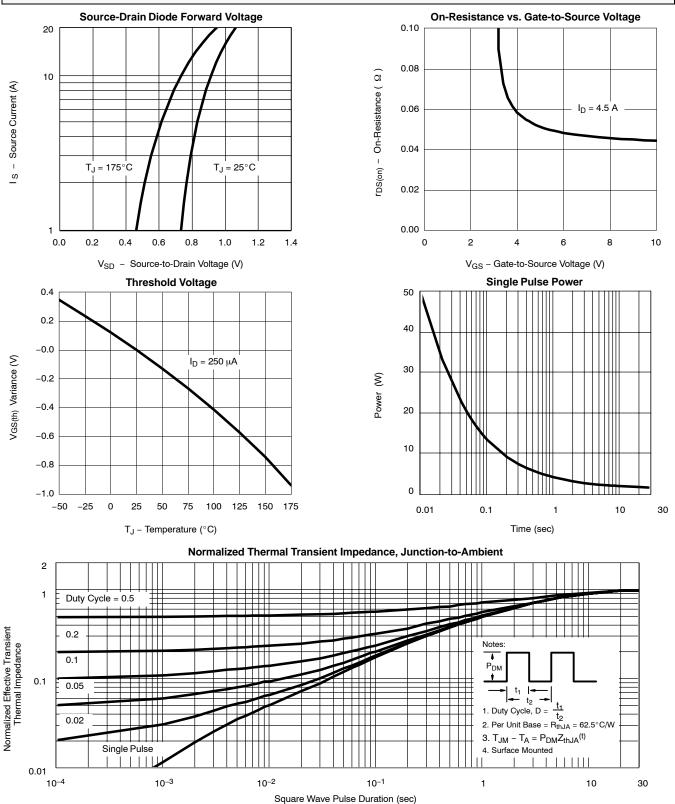


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TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?70157.



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